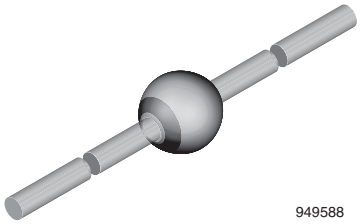
Standard Avalanche Sinterglass Diode



FEATURES

- Glass passivated junction
- Hermetically sealed package
- Controlled avalanche characteristics
- Low reverse current
- High surge current loading
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

RoHS COMPLIANT
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DESIGN SUPPORT TOOLS

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3D Models Available

APPLICATIONS

- Rectification diode, general purpose

MECHANICAL DATA

Case: SOD-64

Terminals: plated axial leads, solderable per MIL-STD-750, method 2026

Polarity: color band denotes cathode end

Mounting position: any

Weight: approx. 858 mg

ORDERING INFORMATION (Example)

DEVICE NAME	ORDERING CODE	TAPED UNITS	MINIMUM ORDER QUANTITY
1N5627	1N5627-TR	2500 per 10" tape and reel	12 500
1N5627	1N5627-TAP	2500 per ammopack	12 500

PARTS TABLE

PART	TYPE DIFFERENTIATION	PACKAGE
1N5624	V_R = 200 V; $I_{F(AV)}$ = 3 A	SOD-64
1N5625	V_R = 400 V; $I_{F(AV)}$ = 3 A	SOD-64
1N5626	V_R = 600 V; $I_{F(AV)}$ = 3 A	SOD-64
1N5627	V_R = 800 V; $I_{F(AV)}$ = 3 A	SOD-64

ABSOLUTE MAXIMUM RATINGS (T_{amb} = 25 °C, unless otherwise specified)

PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT
Reverse voltage = repetitive peak reverse voltage	See electrical characteristics	1N5624	$V_R = V_{RRM}$	200	V
		1N5625	$V_R = V_{RRM}$	400	V
		1N5626	$V_R = V_{RRM}$	600	V
		1N5627	$V_R = V_{RRM}$	800	V
Peak forward surge current	t_p = 10 ms, half sine wave		I_{FSM}	100	A
Repetitive peak forward current			I_{FRM}	18	A
Average forward current			$I_{F(AV)}$	3	A
Pulse avalanche peak power	t_p = 20 µs, half sine wave, T_j = 175 °C		P_R	1000	W
Pulse energy in avalanche mode, non repetitive (inductive load switch off)	$I_{(BR)R}$ = 1 A, T_j = 175 °C		E_R	20	mJ
i^2t-rating			i^2t	40	A^2s
Junction and storage temperature range			$T_j = T_{stg}$	-55 to +175	°C

MAXIMUM THERMAL RESISTANCE (T_{amb} = 25 °C, unless otherwise specified)				
PARAMETER	**TEST CONDITION**	**SYMBOL**	**VALUE**	**UNIT**
Junction ambient	l = 10 mm, T_L = constant	R_{thJA}	25	K/W
	On PC board with spacing 25 mm	R_{thJA}	70	K/W

ELECTRICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)							
PARAMETER	**TEST CONDITION**	**PART**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Forward voltage	I_F = 3 A		V_F	-	-	1	V
Reverse current	$V_R = V_{RRM}$		I_R	-	0.1	1	µA
	$V_R = V_{RRM}$, T_j = 100 °C		I_R	-	5	10	µA
Breakdown voltage	I_R = 100 µA, t_p/T = 0.01, t_p = 0.3 ms		$V_{(BR)}$	-	-	1600	V
Diode capacitance	V_R = 4 V, f = 1 MHz		C_D	-	40	60	pF
Reverse recovery time	I_F = 0.5 A, I_R = 1 A, i_R = 0.25 A		t_{rr}	-	3.5	5	µs
	I_F = 1 A, d_I/d_t = 5 A/µs, V_R = 50 V		t_{rr}	-	4.5	7.5	µs
Reverse recovery charge	I_F = 1 A, d_I/d_t = 5 A/µs		Q_{rr}	-	8	12	µC

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

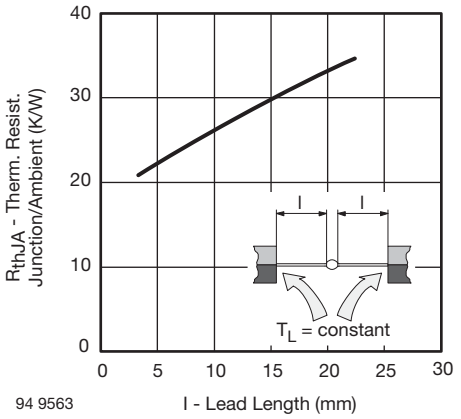


Fig. 1 - Max. Thermal Resistance vs. Lead Length

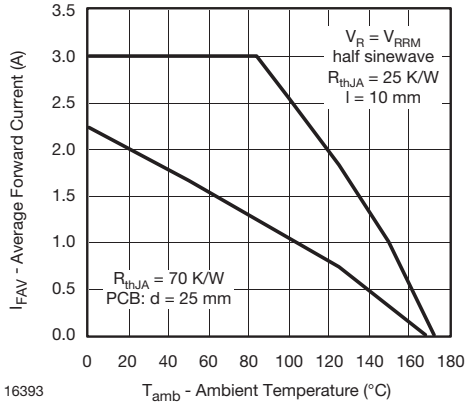


Fig. 3 - Max. Average Forward Current vs. Ambient Temperature

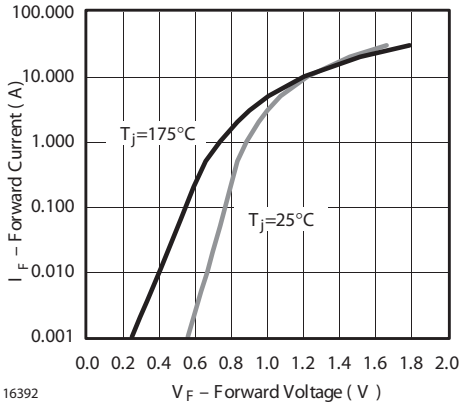


Fig. 2 - Forward Current vs. Forward Voltage

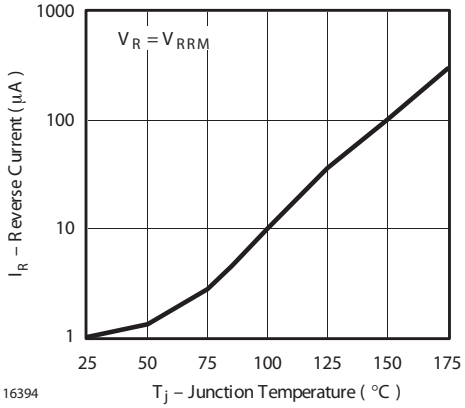


Fig. 4 - Reverse Current vs. Junction Temperature

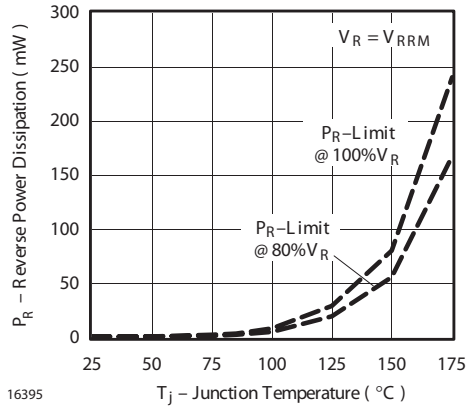


Fig. 5 - Max. Reverse Power Dissipation vs. Junction Temperature

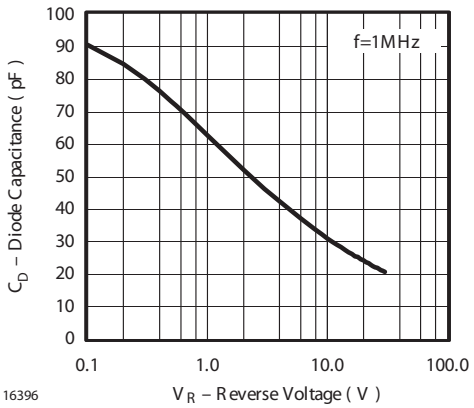
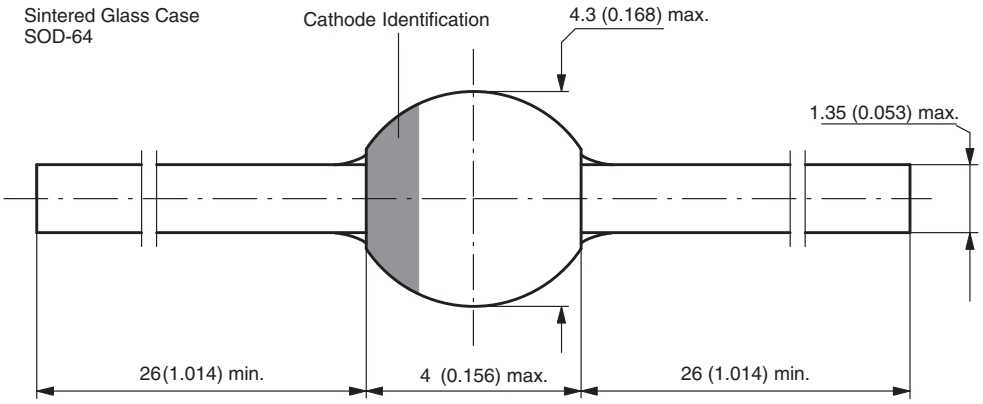


Fig. 6 - Diode Capacitance vs. Reverse Voltage

PACKAGE DIMENSIONS in millimeters (inches): **SOD-64**



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